Indirect Excitons: From the Physics of Cold Bosons to Devices and Back

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exciton - bound pair of electron and hole

 $m_{exciton} = m_{electron} + m_{hole} \ll m_{atom}$

light bosonic particle in semiconductor



Basic physics of cold bosons:

Spontaneous coherence and condensation

Spin currents and spin textures

Transport and localization

Correlations

. . .

Pattern formation

excitons with designed properties

Excitonic devices:

Report of the **Semiconductor Research Corporation** and the **National Science Foundation** workshop to explore future research directions for **energy efficient computing** (Oct 2015) aligns with the Nanotechnology-inspired Grand Challenge for Future Computing and the National Strategic Computing Initiative:

"promising possibility is based on the emergence of devices for direct conversion of photons to excitons. These **excitonic devices**^{*} might enable detection, storage, processing and transmission of data packets without the need for power-hungry electronic circuits"

*P. Andreakou et al., "Optically Controlled Excitonic Transistor," Appl. Phys. Lett. 104, 091101 (2014). How to realize quantum exciton gas?

Transition from classical to quantum gas takes place when thermal de Broglie wavelength is comparable to interparticle separation

3D:
$$\lambda_{dB} = n^{-1/3}$$

 $T_{dB} = \frac{2\pi\hbar^2}{mk_B}n^{2/3}$
 $T_{BEC} = 0.527T_{dB}$
 $m_{exciton} \sim 10^{-6} m_{atom}$
2D: $\lambda_{dB} = n^{-1/2}$
 $T_{dB} = \frac{2\pi\hbar^2}{mk_B}n$
temperature of quantum degeneracy

3D gas of Rb atoms: $n = 10^{15} \text{ cm}^{-3}, m_{atom} = 10^5 m_e \rightarrow T_{dB} \sim 5 \times 10^{-6} \text{ K}$ 2D gas of excitons in GaAs QW $n = 10^{10} \text{ cm}^{-2}, m_{exciton} = 0.2 m_e \rightarrow T_{dB} \sim 3 \text{ K}$

1995 discovery of BEC of atoms

 $\lambda_{dB} = \left(\frac{2\pi\hbar^2}{mk_BT}\right)^{1/2}$

2001
 Eric A. Cornell
 Wolfgang Ketterle
 Carl E. Wieman

How to realize quantum exciton gas?

T_{lattice} << 1 K in He refrigerators

finite lifetime of excitons can result to high exciton temperature: $T_{exciton} >> T_{lattice}$

design excitons with <u>lifetime</u> >> <u>cooling time</u>

Indirect excitons in Coupled Quantum Wells

$10^3 - 10^6$ times longer exciton lifetime due to separation between electron and hole layers

realization of cold exciton gas in separated layers was proposed by Yu.E. Lozovik, V.I. Yudson (1975) T. Fukuzawa, S.S. Kano, T.K. Gustafson, T. Ogawa (1990)

Indirect excitons in Coupled Quantum Wells

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 $m_{exciton} = m_{electron} + m_{hole} \ll m_{atom}$

light bosonic particle in semiconductor

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*P. Andreakou *et al.*, "Optically Controlled Excitonic Transistor," Appl. Phys. Lett. 104, 091101 (2014).

Pattern formation

Exciton rings and macroscopically ordered exciton state

model of

- inner ring: A.L. Ivanov, L. Smallwood, A. Hammack, Sen Yang, L.V. Butov, A.C. Gossard, *EPL* 73, 920 (2006)
- external ring: L.V. Butov, L.S. Levitov, B.D. Simons, A.V. Mintsev, A.C. Gossard, D.S. Chemla, *PRL* 92, 117404 (2004)
 R. Rapaport, G. Chen, D. Snoke, S.H. Simon, L. Pfeiffer, K.West, Y.Liu, S.Denev, *PRL* 92, 117405 (2004)
- MOES: L.S. Levitov, B.D. Simons, L.V. Butov, *PRL* 94, 176404 (2005)

inner ring forms due to transport and cooling of optically generated excitons

emission of indirect excitons

excitons are generated in external ring and LBS rings at ring shaped interface between <u>electron</u>-rich and <u>hole</u>-rich regions

external rings and LBS rings form sources of cold excitons

exciton gas is hot in LBS centers

exciton gas is cold in external ring and LBS rings quantum exciton gas Spontaneous coherence and condensation

Condensation and spontaneous coherence

Louis de Broglie, 1923: all forms of matter have wave as well as particle properties. The wavelength of a matter wave associated with any moving object $\lambda = h/p$

If bosonic particles are cooled down **below the temperature of quantum degeneracy** they can spontaneously form **a coherent state** in which **individual matter waves synchronize and combine**

Theoretical predictions for coherent states in cold exciton systems:

- BEC L.V. Keldysh, A.N. Kozlov, JETP 27, 521 (1968)
- BCS-like condensation L.V. Keldysh, Yu.V. Kopaev, Phys. Solid State 6, 2219 (1965)
- charge-density-wave formation X.M. Chen, J.J. Quinn, PRL 67, 895 (1991)
- condensation with SO coupling Congjun Wu, Ian Mondragon-Shem, arXiv:0809.3532

First order coherence function $g_1(\delta x)$

Pattern of $g_1(\delta x)$ is measured by shift-interferometry $g(t, \mathbf{r}) = \langle E(t' + t, \mathbf{r}' + \mathbf{r})E(t', \mathbf{r}') \rangle / \langle E^2(t', \mathbf{r}') \rangle$

Images produced by arm 1 and 2 of MZ interferometer are shifted to measure interference between emission of excitons separated by δx

Contrast of interference fringes $A_{\text{interf}}(\delta x) \rightarrow g_1(\delta x)$

exciton coherence is imprinted on coherence of their light emission

Emission, interference, coherence degree, and polarization patterns

A.A. High, J.R. Leonard, A.T. Hammack, M.M. Fogler, L.V. Butov, A.V. Kavokin, K.L. Campman, A.C. Gossard, *Nature* 483, 584 (2012) map of coherence degree

coherence is not induced by pumping light and, instead, **is spontaneous** A.A. High, A.T. Hammack,
J.R. Leonard, Sen Yang,
L.V. Butov, T. Ostatnický,
M. Vladimirova, A.V. Kavokin,
K.L. Campman, A.C. Gossard, *PRL* 110, 246403 (2013)

Exciton coherence and spin texture around LBS-ring

Emergence of

- Spontaneous coherence
- Spin polarization vortex

at low T at $r > r_0$

Exciton coherence and spin texture around external ring

Emergence of

- Spontaneous coherence
- Periodic spin texture

at low T at $r > r_0^*$

Theoretical model for MOES

instability requires <u>positive feedback</u> to density variations

$$\frac{\partial n_e}{\partial t} = D_e \nabla^2 n_e - w n_e n_h + J_e$$
$$\frac{\partial n_h}{\partial t} = D_h \nabla^2 n_h - w n_e n_h + J_h$$
$$\frac{\partial n_X}{\partial t} = D_X \nabla^2 n_X + w n_e n_h - n_X / \tau_{opt}$$
$$w \sim 1 + N_{E=0} = e^{\frac{T_{dB}}{T}} = e^{\frac{2\pi h^2}{mgk_B T} n_x}$$

consistent with experimental data

instability results from quantum degeneracy in a cold exciton system due to <u>stimulated kinetics of exciton formation</u>

L.S. Levitov, B.D. Simons, L.V. Butov, PRL 94, 176404 (2005)

Spin currents and spin textures

 $E_d - (g_h + g_e)\mu_B B/2$

 $-\delta_d$

 $k_e \beta_e e^{-i\phi}$

 $-\delta_d$

 $E_d + (g_h + g_e)\mu_B B/2$

 $\hat{H} =$ spins $J_z = +1, -1, +2, -2$ the coherent $k_h \beta_h e^{i\phi}$ spin dynamics is governed by

radial exciton polarization currents are associated with spin currents carried by electrons and holes bound into excitons

electron and hole spin tend to align along the effective magnetic fields given by the Dresselhaus SO interaction

A.A. High, A.T. Hammack, J.R. Leonard, Sen Yang, L.V. Butov, T. Ostatnický, M. Vladimirova, A.V. Kavokin, K.L. Campman, A.C. Gossard, *PRL* 110, 246403 (2013)

The formation of a coherent gas of bosonic pairs – a new mechanism to suppress the spin relaxation

while the spin relaxation times of free electrons and holes can be short, the formation of a coherent gas of their bosonic pairs results in a strong enhancement of their spin relaxation times \rightarrow **long-range spin currents**

measured by polarization resolved imaging

B=0T

$$P_{lin} = \frac{I_x - I_y}{I_x + I_y}$$

-0.3

radial exciton polarization currents are associated with spin currents carried by electrons and holes bound into excitons

A.A. High, A.T. Hammack,
J.R. Leonard, Sen Yang,
L.V. Butov, T. Ostatnický,
M. Vladimirova, A.V. Kavokin,
K.L. Campman, A.C. Gossard, *PRL* 110, 246403 (2013)

B=1T

-0.3

applied magnetic fields bend spin current trajectories

B=2T

$$P_{lin} = \frac{I_x - I_y}{I_x + I_y}$$

-0.3

applied magnetic fields bend spin current trajectories

B=3T

-0.3

applied magnetic fields bend spin current trajectories

B=4T

-0.3

applied magnetic fields bend spin current trajectories

B=5T

-0.3

applied magnetic fields bend spin current trajectories

B=6T

$$P_{lin} = \frac{I_x - I_y}{I_x + I_y}$$

applied magnetic fields bend spin current trajectories

spiral patterns of linear polarization Simulated in-plane exciton polarization $+\pi/2$

B=7T

$$P_{lin} = \frac{I_x - I_y}{I_x + I_y}$$

applied magnetic fields bend spin current trajectories

spiral patterns of linear polarization

spiral direction of exciton polarization current ≠ radial direction of exciton density current Simulated in-plane exciton polarization $+\pi/2$

Excitonic devices

Excitonic devices

potential energy of indirect excitons is controlled by voltage

excitonic circuit devices

- low-energy
- direct link to optical communication
- sub-wavelength footprint

traps and lattices for excitons and other potential landscapes

tool for studying basic properties

Proof-of-principle demonstrations of excitonic devices:

• Excitonic transistor and IC

A.A. High, E.E. Novitskaya, L.V. Butov, M. Hanson, A.C. Gossard, *Science* 321, 229 (2008)

G. Grosso, J. Graves, A.T. Hammack, A.A. High, L.V. Butov, M. Hanson, A.C. Gossard, *Nature Photonics* 3, 577 (2009)

• All-optical excitonic transistors and routers

P. Andreakou, S.V. Poltavtsev, J.R. Leonard, E.V. Calman, M. Remeika, Y.Y. Kuznetsova, L.V. Butov, J. Wilkes, M. Hanson, A.C. Gossard, *Appl. Phys. Lett.* 104, 091101 (2014)

Proof-of-principle demonstrations of excitonic devices:

(b) (c)

(d)

(e)

1500

Laser |

료 1000

500

Time (ns

1000

• Conveyer for excitons, excitonic CCD

A.G. Winbow, J.R. Leonard, M. Remeika,Y.Y. Kuznetsova, A.A. High, A.T. Hammack,L.V. Butov, J. Wilkes, A.A. Guenther, A.L. Ivanov,M. Hanson, A.C. Gossard, *PRL* 106, 196806 (2011)

A.G. Winbow, A.T. Hammack, L.V. Butov, A.C. Gossard, *Nano Lett.* 7, 1349 (2007)

е

Vq = 0

short lifetime

Va finite

long lifetime

electric field

• Ramp for excitons, excitonic diode, with no energy-dissipating voltage gradient

J.R. Leonard, M. Remeika, M.K. Chu, Y.Y. Kuznetsova, A.A. High, L.V. Butov, J. Wilkes, M. Hanson, A.C. Gossard, *Appl. Phys. Lett.* 100, 231106 (2012) Indirect excitons in traps

Condensation of indirect excitons in a trap

With lowering *T*

- IXs condense at the trap bottom
- IX spontaneous coherence emerges

diamond-shaped trap

A.A. High, J.R. Leonard, M. Remeika, L.V. Butov, M. Hanson, A.C. Gossard, *Nano Lett.* 12, 2605 (2012)

Theory: S. Lobanov, N. Gippius, work in progress

Indirect excitons in lattices

Localization-delocalization transition for excitons in lattices

Liner lattices: M. Remeika, J.C. Graves, A.T. Hammack, A.D. Meyertholen, M.M. Fogler, L.V. Butov, M. Hanson, A.C. Gossard, *PRL* 102, 186803 (2009)

2D lattices: M. Remeika, M.M. Fogler, L.V. Butov, M. Hanson, A.C. Gossard, APL 100, 061103 (2012)

Excitonic conveyers / CCD

A.G. Winbow, J.R. Leonard, M. Remeika,Y.Y. Kuznetsova, A.A. High, A.T. Hammack,L.V. Butov, J. Wilkes, A.A. Guenther,A.L. Ivanov, M. Hanson, A.C. Gossard,*PRL* 106, 196806 (2011)

Excitonic stirring potentials

dynamical localization – delocalization transition

M.W. Hasling, Y.Y. Kuznetsova, P. Andreakou, J.R. Leonard, E.V. Calman, C.J. Dorow, L.V. Butov, M. Hanson, A.C. Gossard, *JAP* 117, 023108 (2015)

Correlation parameter determines both the energy shift and the ability of IXs to screen an external potential perturbation

M. Remeika, J.R. Leonard, C.J. Dorow, M.M. Fogler, L.V. Butov, M. Hanson, A.C. Gossard, *Phys. Rev. B* 92, 115311 (2015)

amplitudes of energy and intensity modulations of IX PL

IX correlation parameter

strong IX correlations: $\Delta E \ll \Delta E_{cap}$

Measurement of exciton correlations using electrostatic lattices

Toward high-T superfluidity with indirect excitons in van der Waals heterostructures

Double quantum well van der Waals heterostructure

E.V. Calman, C.J. Dorow, M.M. Fogler, L.V. Butov, S. Hu, A. Mishchenko, A.K. Geim, work in progress

Goal: high-T superfluidity in indirect excitons in artificially structured materials based on transition metal dichalcogenide (TMD) atomically thin layers

$$T_{0} = \frac{2\pi\hbar^{2}}{m_{x}}n = \frac{4\pi m_{e}m_{h}}{m_{x}^{2}}(na_{x}^{2})Ry_{x}$$
$$n^{\max}a_{x}^{2} \sim 0.02$$
$$T_{0}^{\max} \sim 0.06Ry_{x}$$

high $Ry_x \rightarrow high T_0$

M.M. Fogler, L.V. Butov, K.S. Novoselov, *Nature Commun.* 5, 4555 (2014)

Summary

Phenomena in a cold gas of indirect excitons

- Spontaneous coherence and condensation
- Spin currents and spin textures
- Pattern formation: Spatial ordering
- Condensation in a trap
- Localization-delocalization transitions
- Correlations

Proof-of-principle demonstrations of excitonic devices:

- Excitonic transistor and IC
- All-optical excitonic transistors and routers
- Conveyer for excitons, excitonic CCD
- Excitonic photon storage
- Ramp for excitons, excitonic diode, with no energy-dissipating voltage gradient